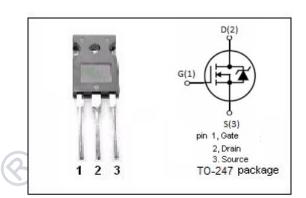


# isc N-Channel MOSFET Transistor

## STW30N65M5

#### **FEATURES**

- · Static Drain-Source On-Resistance
- :  $R_{DS(on)} = 0.139 \Omega (Max)$
- Fast Switching
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



#### **DESCRIPTION**

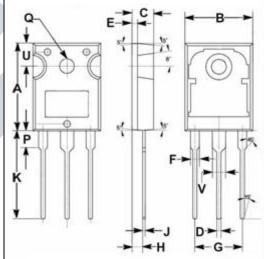
• Designed for use in switch mode power supplies and general purpose applications.



SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	650	V	
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±25	V	
I <sub>D</sub>	Drain Current-Continuous	22	Α	
І <sub>DМ</sub>	Drain Current-Single Pluse	88	Α	
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	140	W	
TJ	Max. Operating Junction Temperature	-55~150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$	

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.89	°C/W



	mm	
DIM	MIN	MAX
Α	19.80	20.20
В	15.40	15.80
C	4.90	5.10
D	0.90	1.10
E	1.40	1.60
F	1.90	2.10
G	10.80	11.00
Н	2.40	2.60
J	0.50	0.70
K	19.50	20.50
Р	3.90	4.10
Q	3.30	3.50
U	5.20	5.40
V	2.90	3.10

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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1mA	650		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> = 0.25mA	3	5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 11A		0.139	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0		1	μ <b>А</b>
		V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0; T <sub>C</sub> =125°C		100	
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 22A; V <sub>GS</sub> = 0		1.5	V

#### **NOTICE:**

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